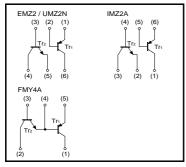
Power management (dual transistors) EMZ2 / UMZ2N / FMY4A / IMZ2A

Feature

1) Both a 2SA1037AK chip and 2SC2412K chip in a EMT or UMT or SMT package.

Equivalent circuits



•Absolute maximum ratings (Ta = 25°C)

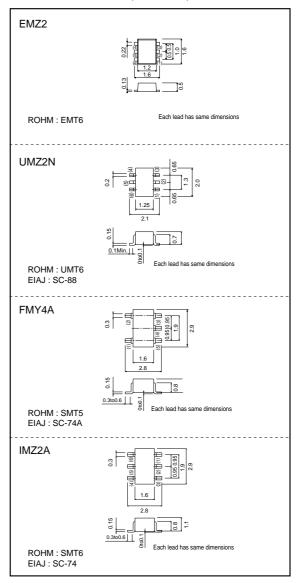
Parameter		Quarket	Lin	nits	Unit	
		Symbol	Tr1 Tr2		Unit	
Collector-base voltage		Vсво	-60	60	V	
Collector-emitter voltage		VCEO	-50	50	V	
Emitter-base voltage		Vebo	-6	7	V	
Collector current		lc	lc –150 150		mA	
Collector power dissipation	EMZ2, UMZ2N	Pc	150 (T	OTAL)	mW	*1
	FMY4A, IMZ2A	FC	300 (TOTAL)		11100	*2
Junction temperature		Tj	1!	50	°C	
Storage temperature		Tstg	-55-	-+150	°C	

*1 120mW per element must not be exceeded. *2 200mW per element must not be exceeded.

•Package, marking, and packaging specifications

Part No.	EMZ2	UMZ2N	FMY4A	IMZ2A
Package	EMT6	UMT6	SMT5	SMT6
Marking	Z2	Z2	Y4	Z2
Code	T2R	TR	T148	T108
Basic ordering unit (pieces)	8000	3000	3000	3000

•External dimensions (Units : mm)



Transistors

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic = -50μA	
Collector-emitter breakdown voltage	BVCEO	-50	-	-	V	Ic = -1mA	
Emitter-base breakdown voltage	ВVево	-6	-	-	V	Iε = -50μA	
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb = -60V	
Emitter cutoff current	Іево	-	-	-0.1	μΑ	Veb = -6V	
Collector-emitter saturation voltage	VCE(sat)	-	-	-0.5	V	lc/ls = -50mA/-5mA	
DC current transfer ratio	hre	120	-	560	-	$V_{CE} = -6V$, $I_C = -1mA$	
Transition frequency	fτ	-	140	-	MHz	Vce = -12V , Ie = 2mA , f = 100MHz	
Output capacitance	Cob	-	4	5	pF	Vсв = -12V, IE = 0A, f = 1MHz	

* Transition frequency of the device.

Tr₂

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	60	-	-	V	Ic = 50μA	
Collector-emitter breakdown voltage	BVCEO	50	-	-	V	lc = 1mA	
Emitter-base breakdown voltage	ВVево	7	-	-	V	IE = 50μA	
Collector cutoff current	Ісво	-	-	0.1	μΑ	Vcb = 60V	
Emitter cutoff current	Іево	-	-	0.1	μΑ	VEB = 7V	
Collector-emitter saturation voltage	VCE(sat)	-	-	0.4	V	lc/ls = 50mA/5mA	
DC current transfer ratio	hfe	120	-	560	-	Vce = 6V , Ic = 1mA	
Transition frequency	fт	-	180	-	MHz	Vce = 12V , Ie = -2mA , f = 100MHz	
Output capacitance	Cob	-	2	3.5	pF	Vcb = 12V , IE = 0A , f = 1MHz	

* Transition frequency of the device.

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